Jonathan Finley

List of Publications by Year
in descending order

278 papers	10,765 citations	28274 55 h-index	40979 93 g-index
282 all docs	282 docs citations	282 times ranked	8524 citing authors

#	Article	IF	Citations
1	Optically programmable electron spin memory using semiconductor quantum dots. Nature, 2004, 432, 81-84.	27.8	858
2	Inverted Electron-Hole Alignment in InAs-GaAs Self-Assembled Quantum Dots. Physical Review Letters, 2000, 84, 733-736.	7.8	467
3	Direct Observation of Controlled Coupling in an Individual Quantum Dot Molecule. Physical Review Letters, 2005, 94, 057402.	7.8	339
4	Direct-bandgap emission from hexagonal Ge and SiGe alloys. Nature, 2020, 580, 205-209.	27.8	231
5	Lasing from individual GaAs-AlGaAs core-shell nanowires up to room temperature. Nature Communications, 2013, 4, 2931.	12.8	207
6	Observation of extremely slow hole spin relaxation in self-assembled quantum dots. Physical Review B, 2007, 76, .	3.2	194
7	Explanation of Photon Correlations in the Far-Off-Resonance Optical Emission from a Quantum-Dotâ€“Cavity System. Physical Review Letters, 2009, 103, 207403.	7.8	182
8	Electrical detection of optically induced charge storage in self-assembled InAs quantum dots. Applied Physics Letters, 1998, 73, 2618-2620.	3.3	173
9	Charged and neutral exciton complexes in individual self-assembledIn(Ga)Asquantum dots. Physical Review B, 2001, 63, .	3.2	164
10	Observation of multicharged excitons and biexcitons in a single InGaAs quantum dot. Physical Review B, 2001, 63, .	3.2	142
11	Growth kinetics in position-controlled and catalyst-free InAs nanowire arrays on Si(111) grown by selective area molecular beam epitaxy. Journal of Applied Physics, 2010, 108, .	2.5	141
12	Emitters of N-photon bundles. Nature Photonics, 2014, 8, 550-555.	31.4	136
13	Site-selectively generated photon emitters in monolayer MoS2 via local helium ion irradiation. Nature Communications, 2019, 10, 2755.	12.8	132
14	Electrical control of spontaneous emission and strong coupling for a single quantum dot. New Journal of Physics, 2009, 11, 023034.	2.9	130
15	Manipulation of the spontaneous emission dynamics of quantum dots in two-dimensional photonic crystals. Physical Review B, 2005, 71, .	3.2	129
16	Investigation of the nonresonant dot-cavity coupling in two-dimensional photonic crystal nanocavities. Physical Review B, 2008, 77, .	3.2	126
17	Direct exciton emission from atomically thin transition metal dichalcogenide heterostructures near the lifetime limit. Scientific Reports, 2017, 7, 12383.	3.3	122
18	Direct Observation of a Noncatalytic Growth Regime for GaAs Nanowires. Nano Letters, 2011, 11, 3848-3854.	9.1	119

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19	Spontaneous Alloy Composition Ordering in GaAs-AlGaAs Coreâ€"Shell Nanowires. Nano Letters, 2013, 13, 1522-1527.	9.1	116
20	A Waveguide-Coupled On-Chip Single-Photon Source. Physical Review X, 2012, 2, .	8.9	115
21	Quantum dot single-photon sources with ultra-low multi-photon probability. Npj Quantum Information, 2018, 4, .	6.7	114
22	The Dielectric Impact of Layer Distances on Exciton and Trion Binding Energies in van der Waals Heterostructures. Nano Letters, 2018, 18, 2725-2732.	9.1	113
23	Phonon-assisted transitions from quantum dot excitons to cavity photons. Physical Review B, 2009, 80, .	3.2	112
24	Monolithically Integrated High-Î² Nanowire Lasers on Silicon. Nano Letters, 2016, 16, 152-156.	9.1	112
25	Fine structure of charged and neutral excitons in InAs-Al0.6Ga0.4Asquantum dots. Physical Review B, 2002, 66, .	3.2	108
26	Quantum-confined Stark shifts of charged exciton complexes in quantum dots. Physical Review B, 2004, 70, .	3.2	108
27	Optically Probing Spin and Charge Interactions in a Tunable Artificial Molecule. Physical Review Letters, 2006, 97, 076403.	7.8	104
28	Dephasing of Exciton Polaritons in Photoexcited InGaAs Quantum Dots in GaAs Nanocavities. Physical Review Letters, 2009, 103, 087405.	7.8	104
29	Silicon photonic crystal nanostructures for refractive index sensing. Applied Physics Letters, 2008, 93, .	3.3	99
30	Three-stage decoherence dynamics of an electron spin qubit in an optically active quantum dot. Nature Physics, 2015, 11, 1005-1008.	16.7	96
31	On-chip time resolved detection of quantum dot emission using integrated superconducting single photon detectors. Scientific Reports, 2013, 3, 1901.	3.3	93
32	Enhanced phonon-assisted absorption in single InAs/GaAs quantum dots. Physical Review B, 2001, 63, .	3.2	90
33	Recent advances in exciton-based quantum information processing in quantum dot nanostructures. New Journal of Physics, 2005, 7, 184-184.	2.9	87
34	Electric-field-dependent carrier capture and escape in self-assembled InAs/GaAs quantum dots. Applied Physics Letters, 2000, 77, 4344-4346.	3.3	86
35	Mutual coupling of two semiconductor quantum dots via an optical nanocavity. Physical Review B, 2010, 82, .	3.2	82
36	Photocurrent spectroscopy of InAs/GaAs self-assembled quantum dots. Physical Review B, 2000, 62, 16784-16791.	3.2	80

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37	Stark Effect Spectroscopy of Mono- and Few-Layer MoS₂. Nano Letters, 2016, 16, 1554-1559.	9.1	80
38	On-Chip Generation, Routing, and Detection of Resonance Fluorescence. Nano Letters, 2015, 15, 5208-5213.	9.1	79
39	Electrical Control of Interdot Electron Tunneling in a Double InGaAs Quantum-Dot Nanostructure. Physical Review Letters, 2012, 108, 197402.	7.8	78
40	Dissipative preparation of the exciton and biexciton in self-assembled quantum dots on picosecond time scales. Physical Review B, 2014, 90, .	3.2	74
41	Enhanced Luminescence Properties of InAsâ€“InAsP Coreâ€“Shell Nanowires. Nano Letters, 2013, 13, 6070-6077.	9.1	73
42	Electric-Field Switchable Second-Harmonic Generation in Bilayer MoS₂ by Inversion Symmetry Breaking. Nano Letters, 2017, 17, 392-398.	9.1	71
43	Absence of vapor-liquid-solid growth during molecular beam epitaxy of self-induced InAs nanowires on Si. Applied Physics Letters, 2011, 98, 123114.	3.3	69
44	Experimental determination ofÎ“â^’Xintervalley transfer mechanisms in GaAs/AlAs heterostructures. Physical Review B, 1996, 54, R8329-R8332.	3.2	68
45	Bandgap Engineering of Graphene Nanoribbons by Control over Structural Distortion. Journal of the American Chemical Society, 2018, 140, 7803-7809.	13.7	68
46	Alloy Fluctuations Act as Quantum Dot-like Emitters in GaAs-AlGaAs Coreâ€“Shell Nanowires. ACS Nano, 2015, 9, 8335-8343.	14.6	65
47	Dynamic Acoustic Control of Individual Optically Active Quantum Dot-like Emission Centers in Heterostructure Nanowires. Nano Letters, 2014, 14, 2256-2264.	9.1	64
48	Resonance Fluorescence of GaAs Quantum Dots with Near-Unity Photon Indistinguishability. Nano Letters, 2019, 19, 2404-2410.	9.1	63
49	Raman spectrum of Janus transition metal dichalcogenide monolayers WSSe and MoSSe. Physical Review B, 2021, 103, .	3.2	63
50	Manipulation of the homogeneous linewidth of an individual In(Ga)As quantum dot. Physical Review B, 2002, 66, .	3.2	61
51	Demonstration of Confined Electron Gas and Steep-Slope Behavior in Delta-Doped GaAs-AlGaAs Coreâ€“Shell Nanowire Transistors. Nano Letters, 2015, 15, 3295-3302.	9.1	60
52	Direct Measurements of Fermi Level Pinning at the Surface of Intrinsically n-Type InGaAs Nanowires. Nano Letters, 2016, 16, 5135-5142.	9.1	60
53	Continuum transitions and phonon coupling in single self-assembled Stranski-Krastanow quantum dots. Physical Review B, 2003, 68, .	3.2	59
54	Coaxial GaAs-AlGaAs core-multishell nanowire lasers with epitaxial gain control. Applied Physics Letters, 2016, 108, .	3.3	59

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55	Directional and Dynamic Modulation of the Optical Emission of an Individual GaAs Nanowire Using Surface Acoustic Waves. Nano Letters, 2011, 11, 1512-1517.	9.1	56
56	High Mobility One- and Two-Dimensional Electron Systems in Nanowire-Based Quantum Heterostructures. Nano Letters, 2013, 13, 6189-6196.	9.1	56
57	Robust valley polarization of helium ion modified atomically thin MoS ₂. 2D Materials, 2018, 5, 011007.	4.4	55
58	High compositional homogeneity in In-rich InGaAs nanowire arrays on nanoimprinted SiO₂/Si (111). Applied Physics Letters, 2012, 101, 043116.	3.3	54
59	Discrete interactions between a few interlayer excitons trapped at a MoSe2â€“WSe2 heterointerface. Npj 2D Materials and Applications, 2020, 4, .	7.9	54
60	Signatures of two-photon pulses from a quantum two-level system. Nature Physics, 2017, 13, 649-654.	16.7	53
61	Coupling Single Photons from Discrete Quantum Emitters in WSe₂ to Lithographically Defined Plasmonic Slot Waveguides. Nano Letters, 2018, 18, 6812-6819.	9.1	53
62	A 2D Semiconductorâ€“Selfâ€Assembled Monolayer Photoswitchable Diode. Advanced Materials, 2015, 27, 1426-1431.	21.0	52
63	Atomistic defects as single-photon emitters in atomically thin MoS2. Applied Physics Letters, 2020, 117, .	3.3	51
64	Temporal monitoring of nonresonant feeding of semiconductor nanocavity modes by quantum dot multiexciton transitions. Physical Review B, 2010, 81, .	3.2	50
65	Tunable Quantum Confinement in Ultrathin, Optically Active Semiconductor Nanowires Via Reverseâ€Reaction Growth. Advanced Materials, 2015, 27, 2195-2202.	21.0	50
66	Dynamic acousto-optic control of a strongly coupled photonic molecule. Nature Communications, 2015, 6, 8540.	12.8	50
67	Surface plasmon resonance spectroscopy of single bowtie nano-antennas using a differential reflectivity method. Scientific Reports, 2016, 6, 23203.	3.3	49
68	GaAsâ€“AlGaAs coreâ€“shell nanowire lasers on silicon: invited review. Semiconductor Science and Technology, 2017, 32, 053001.	2.0	48
69	Engineering the Luminescence and Generation of Individual Defect Emitters in Atomically Thin MoS₂. ACS Photonics, 2021, 8, 669-677.	6.6	48
70	Crystal Phase Quantum Dots in the Ultrathin Core of GaAsâ€“AlGaAs Coreâ€“Shell Nanowires. Nano Letters, 2015, 15, 7544-7551.	9.1	47
71	Role of microstructure on optical properties in high-uniformity In<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mrow><mml:mn>1</mml:mn><mml:mo>âˆ'</mml:mo><mml:mi>x</mml:mi></mml:mrow></mml:msub></mml:math>Ga<mml xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mi>x</mml:mi></mml:msub></mml:math>As nanowire arrays: Evidence of a wider wurtzite band gap. Physical Review B, 2013, 87, .	3.2	46
72	Lattice-Matched InGaAsâ€“InAlAs Coreâ€“Shell Nanowires with Improved Luminescence and Photoresponse Properties. Nano Letters, 2015, 15, 3533-3540.	9.1	46

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73	Tuning Lasing Emission toward Long Wavelengths in GaAs-(In,Al)GaAs Coreâ€“Multishell Nanowires. Nano Letters, 2018, 18, 6292-6300.	9.1	43
74	Progress towards single spin optoelectronics using quantum dot nanostructures. Solid State Communications, 2005, 135, 591-601.	1.9	42
75	Climbing the Jaynesâ€“Cummings ladder by photon counting. Journal of Nanophotonics, 2012, 6, 061803.	1.0	42
76	Signatures of a degenerate many-body state of interlayer excitons in a van der Waals heterostack. Physical Review Research, 2020, 2, .	3.6	42
77	Wavelength selective charge storage in self-assembled InGaAs/GaAs quantum dots. Applied Physics Letters, 2003, 83, 443-445.	3.3	41
78	Direct observation of acoustic phonon mediated relaxation between coupled exciton states in a single quantum dot molecule. Physical Review B, 2006, 74, .	3.2	41
79	Highly efficient single-photon emission from single quantum dots within a two-dimensional photonic band-gap. Physical Review B, 2008, 77, .	3.2	41
80	Acoustically regulated carrier injection into a single optically active quantum dot. Physical Review B, 2013, 88, .	3.2	41
81	Emergence of Photoswitchable States in a Grapheneâ€“Azobenzeneâ€“Au Platform. Nano Letters, 2014, 14, 6823-6827.	9.1	40
82	Charge and spin readout scheme for single self-assembled quantum dots. Physical Review B, 2008, 77, .	3.2	38
83	Manganese doping for enhanced magnetic brightening and circular polarization control of dark excitons in paramagnetic layered hybrid metal-halide perovskites. Nature Communications, 2021, 12, 3489.	12.8	38
84	Rate-limiting mechanisms in high-temperature growth of catalyst-free InAs nanowires with large thermal stability. Nanotechnology, 2012, 23, 235602.	2.6	37
85	Diameter dependent optical emission properties of InAs nanowires grown on Si. Applied Physics Letters, 2012, 101, 053103.	3.3	36
86	High-fidelity optical preparation and coherent Larmor precession of a single hole in an (In,Ga)As quantum dot molecule. Physical Review B, 2012, 85, .	3.2	36
87	Gate-Switchable Arrays of Quantum Light Emitters in Contacted Monolayer MoS₂ van der Waals Heterodevices. Nano Letters, 2021, 21, 1040-1046.	9.1	36
88	Long-range ordered self-assembled InAs quantum dots epitaxially grown on (110) GaAs. Applied Physics Letters, 2004, 85, 4750-4752.	3.3	35
89	Ultrafast Photodetection in the Quantum Wells of Single AlGaAs/GaAs-Based Nanowires. Nano Letters, 2015, 15, 6869-6874.	9.1	35
90	Toward Plasmonic Tunnel Gaps for Nanoscale Photoemission Currents by On-Chip Laser Ablation. Nano Letters, 2019, 19, 1172-1178.	9.1	35

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91	Observation and explanation of strong electrically tunable exciton<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mi>g</mml:mi></mml:mrow></mml:math>factors in composition engineered In(Ga)As quantum dots. Physical Review B, 2011, 83, .	3.2	34
92	Effect of interwire separation on growth kinetics and properties of site-selective GaAs nanowires. Applied Physics Letters, 2014, 105, .	3.3	34
93	Direct Coupling of Coherent Emission from Site-Selectively Grown IIIâ€"V Nanowire Lasers into Proximal Silicon Waveguides. ACS Photonics, 2017, 4, 2537-2543.	6.6	34
94	Crux of Using the Cascaded Emission of a Three-Level Quantum Ladder System to Generate Indistinguishable Photons. Physical Review Letters, 2020, 125, 233605.	7.8	34
95	Efficient spatial redistribution of quantum dot spontaneous emission from two-dimensional photonic crystals. Applied Physics Letters, 2007, 91, .	3.3	33
96	Surface acoustic wave regulated single photon emission from a coupled quantum dotâ€"nanocavity system. Applied Physics Letters, 2016, 109, .	3.3	33
97	Luminescence spectra of quantum dots in microcavities. III. Multiple quantum dots. Physical Review B, 2011, 84, .	3.2	32
98	Tuning the optical emission of MoS2 nanosheets using proximal photoswitchable azobenzene molecules. Applied Physics Letters, 2014, 105, .	3.3	32
99	Virtual Proofs of Reality and their Physical Implementation. , 2015, , .		32
100	Slow light enhanced gas sensing in photonic crystals. Optical Materials, 2018, 76, 106-110.	3.6	31
101	Probing the trapping and thermal activation dynamics of excitons at single twin defects in GaAsâ€"AlGaAs coreâ€"shell nanowires. New Journal of Physics, 2013, 15, 113032.	2.9	30
102	Quantum Effects in Higher-Order Correlators of a Quantum-Dot Spin Qubit. Physical Review Letters, 2016, 117, 027402.	7.8	30
103	Observation of an electrically tunable exciton g factor in InGaAs/GaAs quantum dots. Applied Physics Letters, 2010, 96, 053113.	3.3	29
104	Pulsed Rabi oscillations in quantum two-level systems: beyond the area theorem. Quantum Science and Technology, 2018, 3, 014006.	5.8	29
105	Widely tunable alloy composition and crystal structure in catalyst-free InGaAs nanowire arrays grown by selective area molecular beam epitaxy. Applied Physics Letters, 2016, 108, .	3.3	27
106	Enhanced photoluminescence emission from two-dimensional silicon photonic crystal nanocavities. New Journal of Physics, 2010, 12, 053005.	2.9	26
107	Photocurrents in a Single InAs Nanowire/Silicon Heterojunction. ACS Nano, 2015, 9, 9849-9858.	14.6	26
108	The Native Material Limit of Electron and Hole Mobilities in Semiconductor Nanowires. ACS Nano, 2016, 10, 4942-4953.	14.6	26

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109	Ultrafast few-fermion optoelectronics in a single self-assembled<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mtext>In</mml:mtext><mml:mtext>Ga</mml:mtext><mml:mtext>As</mml:mtext><mml:mo>/</m dot. Physical Review B, 2010, 82, .	3.2	25
110	All optical quantum control of a spin-quantum state and ultrafast transduction into an electric current. Scientific Reports, 2013, 3, 1906.	3.3	25
111	Optical properties and interparticle coupling of plasmonic bowtie nanoantennas on a semiconducting substrate. Physical Review B, 2014, 90, .	3.2	25
112	Coulomb Mediated Hybridization of Excitons in Coupled Quantum Dots. Physical Review Letters, 2016, 116, 077401.	7.8	25
113	3D Deep Learning Enables Accurate Layer Mapping of 2D Materials. ACS Nano, 2021, 15, 3139-3151.	14.6	25
114	Level-Crossing Transition in the Cluster CompoundsNb6I11and HNb6I11. Physical Review Letters, 1981, 46, 1472-1475.	7.8	24
115	Role of theXminimum in transport through AlAs single-barrier structures. Physical Review B, 1998, 58, 10619-10628.	3.2	24
116	Highly nonlinear excitonic Zeeman spin splitting in composition-engineered artificial atoms. Physical Review B, 2012, 85, .	3.2	24
117	Continuous wave lasing from individual GaAs-AlGaAs core-shell nanowires. Applied Physics Letters, 2016, 108, .	3.3	24
118	Impact of substrate induced band tail states on the electronic and optical properties of MoS2. Applied Physics Letters, 2019, 115, .	3.3	24
119	Optomechanical wave mixing by a single quantum dot. Optica, 2021, 8, 291.	9.3	24
120	Spin-preserving ultrafast carrier capture and relaxation in InGaAs quantum dots. Applied Physics Letters, 2005, 87, 153113.	3.3	23
121	Direct observation of metastable hot trions in an individual quantum dot. Physical Review B, 2011, 84, .	3.2	23
122	Electrical control of the excitonâ€“biexciton splitting in self-assembled InGaAs quantum dots. Nanotechnology, 2011, 22, 325202.	2.6	23
123	Independent dynamic acousto-mechanical and electrostatic control of individual quantum dots in a LiNbO3-GaAs hybrid. Applied Physics Letters, 2015, 106, .	3.3	23
124	Controlling exciton many-body states by the electric-field effect in monolayer <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:msub><mml:mrow><mml:mi>MoS</mml:mi></mml:mrow><mml:mn>2</m Physical Review Research, 2021, 3, .	3.6	23
125	Radio frequency occupancy state control of a single nanowire quantum dot. Journal Physics D: Applied Physics, 2014, 47, 394011.	2.8	22
126	Origin of Antibunching in Resonance Fluorescence. Physical Review Letters, 2020, 125, 170402.	7.8	22

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127	Electrically probing photonic bandgap phenomena in contacted defect nanocavities. Applied Physics Letters, 2007, 91, 201111.	3.3	21
128	Optically monitoring electron spin relaxation in a single quantum dot using a spin memory device. Physical Review B, 2010, 82, .	3.2	20
129	Stimulated Generation of Indistinguishable Single Photons from a Quantum Ladder System. Physical Review Letters, 2022, 128, 093603.	7.8	20
130	Electroluminescence spectroscopy in a high magnetic field of the ballistic-electron energy distribution in single-barrier heterostructures. Physical Review B, 1995, 51, 5562-5565.	3.2	19
131	Efficient and selective cavity-resonant excitation for single photon generation. New Journal of Physics, 2009, 11, 013031.	2.9	19
132	Selective optical charge generation, storage, and readout in a single self-assembled quantum dot. Applied Physics Letters, 2009, 94, .	3.3	19
133	Broadband Purcell enhanced emission dynamics of quantum dots in linear photonic crystal waveguides. Journal of Applied Physics, 2012, 112, .	2.5	19
134	Optimisation of NbN thin films on GaAs substrates for in-situ single photon detection in structured photonic devices. Journal of Applied Physics, 2013, 113, 143507.	2.5	19
135	Quantumâ€Confinementâ€Enhanced Thermoelectric Properties in Modulationâ€Doped GaAsâ€“AlGaAs Coreâ€“Shell Nanowires. Advanced Materials, 2020, 32, e1905458.	21.0	19
136	Modal gain and lasing states in InAs/GaAs self-organized quantum dot lasers. Journal of Applied Physics, 2000, 87, 615-617.	2.5	18
137	Temperature-induced carrier escape processes studied in absorption of individualInxGa1âˆ’xAsquantum dots. Physical Review B, 2004, 69, .	3.2	18
138	Quantum Transport and Sub-Band Structure of Modulation-Doped GaAs/AlAs Coreâ€“Superlattice Nanowires. Nano Letters, 2017, 17, 4886-4893.	9.1	18
139	Low-threshold strain-compensated InGaAs/(In,Al)GaAs multi-quantum well nanowire lasers emitting near 1.3 Î¼m at room temperature. Applied Physics Letters, 2021, 118, .	3.3	18
140	Unveiling the Zero-Phonon Line of the Boron Vacancy Center by Cavity-Enhanced Emission. Nano Letters, 2022, 22, 5137-5142.	9.1	18
141	Spin crossover transition in the cluster compoundsNb6I11and HNb6I11. Physical Review B, 1981, 24, 1323-1332.	3.2	17
142	Carrier dynamics in short wavelength self-assembled InAs/Al0.6Ga0.4As quantum dots with indirect barriers. Journal of Applied Physics, 2003, 93, 3524-3528.	2.5	17
143	Excited state quantum couplings and optical switching of an artificial molecule. Physical Review B, 2011, 84, .	3.2	17
144	Suppression of alloy fluctuations in GaAs-AlGaAs core-shell nanowires. Applied Physics Letters, 2016, 109, .	3.3	17

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145	Ultrathin catalyst-free InAs nanowires on silicon with distinct 1D sub-band transport properties. Nanoscale, 2020, 12, 21857-21868.	5.6	17
146	ResonantÎ“âˆ’Xâˆ’Î“magnetotunneling in GaAs-AlAs-GaAs heterostructures. Physical Review B, 1996, 54, R5251-R5254.	3.2	16
147	Electronic properties of InAs/GaAs self-assembled quantum dots studied by photocurrent spectroscopy. Physica E: Low-Dimensional Systems and Nanostructures, 2001, 9, 106-113.	2.7	16
148	Nonlinear optical response of a single self-assembled InGaAs quantum dot: A femtojoule pump-probe experiment. Applied Physics Letters, 2006, 88, 203110.	3.3	16
149	Surface acoustic wave controlled charge dynamics in a thin InGaAs quantum well. JETP Letters, 2012, 95, 575-580.	1.4	16
150	Optical control of nonlinearly dressed states in an individual quantum dot. Physical Review B, 2016, 93, .	3.2	16
151	Optical characterization of silicon on insulator photonic crystal nanocavities infiltrated with colloidal PbS quantum dots. Applied Physics Letters, 2007, 91, 233111.	3.3	15
152	An atomically resolved study of InGaAs quantum dot layers grown with an indium flush step. Nanotechnology, 2010, 21, 215705.	2.6	15
153	Probing ultrafast carrier tunneling dynamics in individual quantum dots and molecules. Annalen Der Physik, 2013, 525, 49-58.	2.4	15
154	Ultracompact Photodetection in Atomically Thin MoSe₂. ACS Photonics, 2019, 6, 1902-1909.	6.6	15
155	Development of a multilayer thinâ€film solar control windshield. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 1996, 14, 739-746.	2.1	14
156	A carrier relaxation bottleneck probed in single InGaAs quantum dots using integrated superconducting single photon detectors. Applied Physics Letters, 2014, 105, 081107.	3.3	14
157	Integrated superconducting detectors on semiconductors for quantum optics applications. Applied Physics B: Lasers and Optics, 2016, 122, 1.	2.2	14
158	Long-term mutual phase locking of picosecond pulse pairs generated by a semiconductor nanowire laser. Nature Communications, 2017, 8, 15521.	12.8	14
159	Carrier concentration dependent photoluminescence properties of Si-doped InAs nanowires. Applied Physics Letters, 2018, 112, .	3.3	14
160	Breakdown of Corner States and Carrier Localization by Monolayer Fluctuations in Radial Nanowire Quantum Wells. Nano Letters, 2019, 19, 3336-3343.	9.1	14
161	Demonstration of <i>n</i>-type behavior in catalyst-free Si-doped GaAs nanowires grown by molecular beam epitaxy. Applied Physics Letters, 2020, 116, .	3.3	14
162	Shape control of quantum dots studied by cross-sectional scanning tunneling microscopy. Journal of Applied Physics, 2011, 109, 102413.	2.5	13

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163	Enhanced optical activity of atomically thin MoSe 2 proximal to nanoscale plasmonic slot-waveguides. 2D Materials, 2017, 4, 021011.	4.4	13
164	Correlated Chemical and Electrically Active Dopant Analysis in Catalyst-Free Si-Doped InAs Nanowires. ACS Nano, 2018, 12, 1603-1610.	14.6	13
165	He-Ion Microscopy as a High-Resolution Probe for Complex Quantum Heterostructures in Coreâ€"Shell Nanowires. Nano Letters, 2018, 18, 3911-3919.	9.1	13
166	Line-Scan Hyperspectral Imaging Microscopy with Linear Unmixing for Automated Two-Dimensional Crystals Identification. ACS Photonics, 2020, 7, 1216-1225.	6.6	13
167	Optical properties of single charge tuneable InGaAs quantum dots. Physica E: Low-Dimensional Systems and Nanostructures, 2002, 13, 127-130.	2.7	12
168	Correlation between emission intensity of self-assembled germanium islands and quality factor of silicon photonic crystal nanocavities. Physical Review B, 2011, 84, .	3.2	12
169	Nonresonant feeding of photonic crystal nanocavity modes by quantum dots. Journal of Applied Physics, 2011, 109, 102404.	2.5	12
170	Microscopic nature of crystal phase quantum dots in ultrathin GaAs nanowires by nanoscale luminescence characterization. New Journal of Physics, 2016, 18, 063009.	2.9	12
171	GaN Nanowire Arrays for Efficient Optical Read-Out and Optoelectronic Control of NV Centers in Diamond. Nano Letters, 2018, 18, 3651-3660.	9.1	12
172	Bright Electrically Controllable Quantumâ€Dotâ€Molecule Devices Fabricated by In Situ Electronâ€Beam Lithography. Advanced Quantum Technologies, 2021, 4, 2100002.	3.9	12
173	Resonance-fluorescence spectral dynamics of an acoustically modulated quantum dot. Physical Review Research, 2021, 3, .	3.6	12
174	Observation of ballistic transport in double-barrier resonant-tunneling structures by electroluminescence spectroscopy. Physical Review B, 1994, 50, 4885-4888.	3.2	11
175	A three-dimensional silicon photonic crystal nanocavity with enhanced emission from embedded germanium islands. New Journal of Physics, 2012, 14, 083035.	2.9	11
176	Controlled tunneling-induced dephasing of Rabi rotations for high-fidelity hole spin initialization. Physical Review B, 2015, 92, .	3.2	11
177	Emission redistribution from a quantum dot-bowtie nanoantenna. Journal of Nanophotonics, 2016, 10, 033509.	1.0	11
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